





#### NPN DUAL SMALL SIGNAL SURFACE MOUNT TRANSISTOR

### **Features**

- Epitaxial Die Construction
- Ultra-Small Surface Mount Package
- Lead Free By Design/RoHS Compliant (Note 3)
- "Green" Device (Note 4)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT-563
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Copper leadframe.
  Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 2
- Ordering Information: See Page 2
- Weight: 0.002 grams (approximate)



**Device Schematic** 



Top View

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Bottom View

## **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	50	V
Collector-Emitter Voltage	$V_{CEO}$	45	V
Emitter-Base Voltage	V <sub>EBO</sub>	6.0	V
Collector Current	lc	100	mA

#### Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 2)	$P_{D}$	150	mW
Thermal Resistance, Junction to Ambient (Note 2)	$R_{ hetaJA}$	833	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

## **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	(Note 5)	V <sub>(BR)CBO</sub>	50	_	_	V	$I_C = 10\mu A, I_B = 0$
Collector-Emitter Breakdown Voltage	(Note 5)	V <sub>(BR)CEO</sub>	45	_	_	V	$I_C = 10 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	(Note 5)	$V_{(BR)EBO}$	6	_	_	V	$I_E = 1\mu A, I_C = 0$
DC Current Gain	(Note 5)	h <sub>FE</sub>	200	290	450	_	$V_{CE} = 5.0V, I_{C} = 2.0mA$
Collector-Emitter Saturation Voltage	(Note 5)	V <sub>CE(SAT)</sub>	1	_	100 300	mV	$I_C = 10$ mA, $I_B = 0.5$ mA $I_C = 100$ mA, $I_B = 5.0$ mA
Base-Emitter Saturation Voltage	(Note 5)	V <sub>BE(SAT)</sub>		700 900	_	mV	$I_C = 10 \text{mA}, I_B = 0.5 \text{mA}$ $I_C = 100 \text{mA}, I_B = 5.0 \text{mA}$
Base-Emitter Voltage	(Note 5)	V <sub>BE</sub>	580 —	660 —	700 770	mV	$V_{CE} = 5.0V, I_{C} = 2.0mA$ $V_{CE} = 5.0V, I_{C} = 10mA$
Collector-Emitter Cutoff Current	(Note 5)	I <sub>CBO</sub>	_	_	15 5.0	nΑ μΑ	V <sub>CB</sub> = 30V V <sub>CB</sub> = 30V, T <sub>A</sub> = 150°C
Gain Bandwidth Product		f⊤	100	_	_	MHz	$V_{CE} = 5.0V, I_{C} = 10mA,$ f = 100MHz
Output Capacitance		C <sub>OBO</sub>	_	_	4.5	pF	V <sub>CB</sub> = 10V, f = 1.0MHz
Noise Figure		NF	_	_	10	dB	$V_{CE} = 5V$ , $R_S = 2.0k\Omega$ , $f = 1.0kHz$ , $BW = 200Hz$

Notes:

- 1. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways).
- 2. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 3. No purposefully added lead.
- 4. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php
- Short duration pulse test used to minimize self-heating effect.



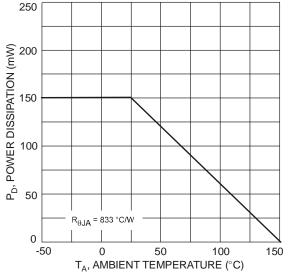


Fig. 1 Power Dissipation vs. Ambient Temperature (Note 2)

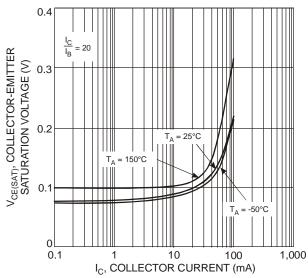


Fig. 3 Typical Collector Emitter Saturation Voltage vs. Collector Current

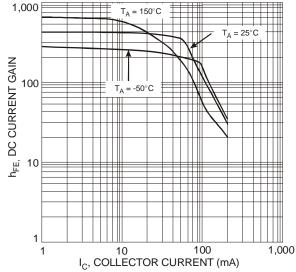


Fig. 2 Typical DC Current Gain vs. Collector Current

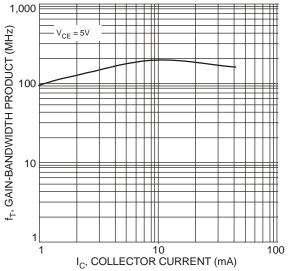


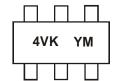
Fig. 4 Typical Gain-Bandwidth Product vs. Collector Current

### Ordering Information (Note 6)

Part Number	Case	Packaging
BC847BVC-7	SOT-563	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## Marking Information



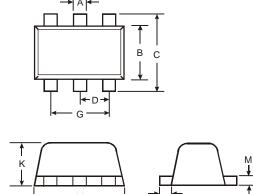
4VK = Product Type Marking Code YM = Date Code Marking Y = Year (ex: S = 2005) M = Month (ex: 9 = September)

Date Code Key

Year	2005	2006	2007	2008	200	9 20	10	2011	2012	2013	2014	2015
Code	S	Т	U	V	W		X	Υ	Z	Α	В	С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	y Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

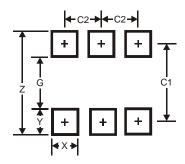


# **Package Outline Dimensions**



SOT-563						
Dim	Min	Max	Тур			
Α	0.15	0.30	0.20			
В	1.10	1.25	1.20			
С	1.55	1.70	1.60			
D	-	-	0.50			
G	0.90	1.10	1.00			
Н	1.50	1.70	1.60			
K	0.55	0.60	0.60			
L	0.10	0.30	0.20			
M	0.10	0.18	0.11			
All	All Dimensions in mm					

# **Suggested Pad Layout**



Dimensions	Value (in mm)
Z	2.2
G	1.2
Х	0.375
Y	0.5
C1	1.7
C2	0.5



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